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- Small-Signal Bandwidth . . . 15 MHz Typ
- Slew Rate . . . 50 V/μs Min
- Bias Current . . . 250 nA Max (LM118, LM218)
- Supply Voltage Range . . . ±5 V to ±20 V
- Internal Frequency Compensation
- Input and Output Overload Protection
- Same Pin Assignments as General-Purpose Operational Amplifiers

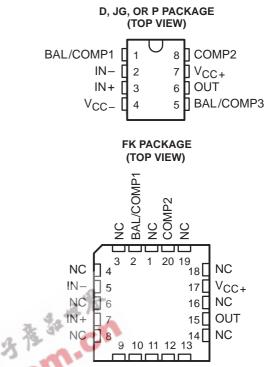
description

The LM118, LM218, and LM318 are precision, fast operational amplifiers designed for applications requiring wide bandwidth and high slew rate. They feature a factor-of-ten increase in speed over general-purpose devices without sacrificing dc performance.

These operational amplifiers have internal unity-gain frequency compensation. This considerably simplifies their application, since no external components are necessary for operation. However, unlike most internally compensated amplifiers, external frequency compensation may be added for optimum performance. For inverting applications, feed-forward compensation boosts the slew rate to over 150 V/µs and almost double the bandwidth. Overcompensation can be used with the amplifier for greater stability when maximum bandwidth is not needed. Further, a single capacitor may be added to reduce the settling time for 0.1% error band to under 1 µs.

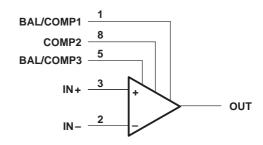
The high speed and fast settling time of these operational amplifiers make them useful in A/D converters, oscillators, active filters, sample-and-hold circuits, and general-purpose amplifiers.

The LM118 is characterized for operation from –55°C to 125°C. The LM218 is characterized for operation from –25°C to 85°C, and the LM318 is characterized for operation from 0°C to 70°C.



NC - No internal connection

symbol



Pin numbers shown are for the D, JG, and P packages.

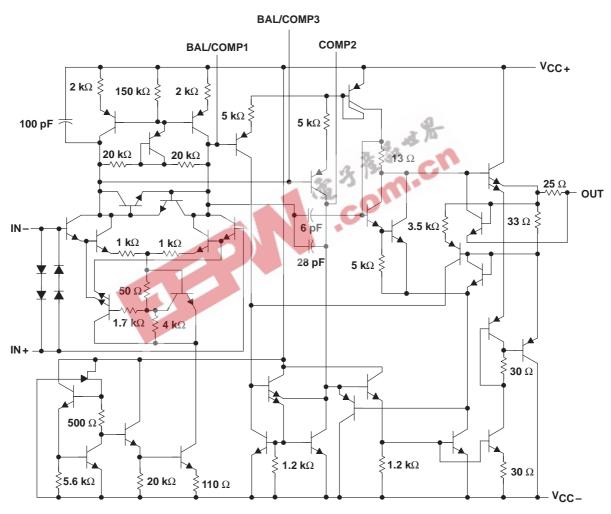
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AVAILABLE OPTIONS

	V max	PACKAGE									
TA	V _{IO} max AT 25°C	SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)						
0°C to 70°C	10 mV	LM318D	_	_	LM318P						
−25°C to 85°C	4 mV	LM218D	_		LM218P						
−55°C to 125°C	4 mV	LM118D	LM118FK	LM118JG	LM118P						

The D package is available taped and reeled. Add the suffix R to the device type (e.g., LM318DR).

schematic



Component values shown are nominal.



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

	LM118	LM218	LM318	UNIT		
Supply voltage, V _{CC+} (see Note 1)	20	20	20	V		
Supply voltage, V _{CC} (see Note 1)	-20	-20	-20	V		
Input voltage, V _I (either input, see Notes 1 and 2)	±15	±15	±15	V		
Differential input current, V _{ID} (see Note 3)	±10	±10	±10	mA		
Duration of output short circuit (see Note 4)	unlimited	unlimited	unlimited			
Continuous total power dissipation	See Dissipation Rating Table					
Operating free-air temperature range, TA	-55 to 125	-25 to 85	0 to 70	°C		
Storage temperature range	-65 to 150	-65 to 150	-65 to 50	°C		
Case temperature for 60 seconds	260			°C		
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260	260	260	°C		
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	300			°C		

- NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC+} and V_{CC-}.
 - 2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.
 - 3. The inputs are shunted with two opposite-facing base-emitter diodes for overvoltage protection. Therefore, excessive current flows if a different input voltage in excess of approximately 1 V is applied between the inputs unless some limiting resistance is used.
 - 4. The output can be shorted to ground or either power supply. For the LM118 and LM218 only, the unlimited duration of the short circuit applies at (or below) 85°C case temperature or 75°C free-air temperature.

DISSIPATION RATING TABLE

				-	~ 3		
PACKAGE	$\begin{array}{c} \text{T}_{\mbox{A}} \leq 25^{\circ} \mbox{C} \\ \text{POWER RATING} \end{array}$	DERATING FACTOR	. 1	ERATE BOVE TA	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D	500 mV	5.8 mW/°C		64°C	464 mW	377 mW	145 mW
FK	500 mV	11.0 mW/°C		105°C	500 mW	500 mW	275 mW
JG	500 mV	8.4 mW/°C	T	90°C	500 mW	500 mW	210 mW
Р	500 mV	8.0 mW/°C		88°C	500 mW	500 mW	200 mW



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electrical characteristics at specified free-air temperature (see Note 5)

PARAMETER		TEST	- +	LM1	18, LM2	18	LM318			UNIT	
		CONDITIONS†	T _A ‡	MIN	TYP	MAX	MIN	TYP	MAX	UNII	
V. 0	Input offset voltage	Vo = 0	25°C		2	4		4	10	mV	
VIO	input onset voltage	VO = 0	Full range			6			15	miv	
lio.	Input offset current	V _O = 0	25°C		6	50		30	200	nA	
ΙO	input onset current	νO = 0	Full range			100			300		
l.s	Input bigg ourrent	Vo = 0	25°C		120	250		150	500	- 4	
IВ	Input bias current	VO = 0	Full range			500			750	nA	
VICR	Common-mode input voltage range	$V_{CC\pm} = \pm 15 \text{ V}$	Full range	± 11.5			±11.5			V	
V _{OM}	Maximum peak output voltage swing	$V_{CC\pm} = \pm 15 \text{ V},$ $R_L = 2 \text{ k}\Omega$	Full range	±12	±13		±12	±13		V	
	Large-signal differential	$V_{CC\pm} = \pm 15 \text{ V},$	25°C	50	200		25	200		.,, .,	
AVD	voltage amplification	$V_O = \pm 10 \text{ V},$ $R_L \ge 2 \text{ k}\Omega$	Full range	25			20			· V/mV	
B ₁	Unity-gain bandwidth	$V_{CC\pm} = \pm 15 \text{ V}$	25°C		15			15		MHz	
rį	Input resistance		25°C	1*	3	2.	0.5	3		ΜΩ	
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICR} min	Full range	80	100	114	70	100		dB	
ksvr	Supply-voltage rejection ratio (ΔV _{CC} /ΔV _{IO})		Full range	70	80	CI	65	80		dB	
ICC	Supply current	$V_O = 0$, No load	2 5°C		5	8		5	10	mA	

^{*} On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

NOTE 5: Unless otherwise noted, $V_{CC} = \pm 5 \text{ V}$ to $\pm 20 \text{ V}$. All typical values are at $V_{CC} \pm 15 \text{ V}$ and $T_A = 25^{\circ}\text{C}$.

operating characteristics, $V_{CC\pm} = \pm 15 \text{ V}$, $T_A = 25^{\circ}\text{C}$

PARAMETER			Т	EST CONDITION	MIN	TYP	MAX	UNIT				
SR	Slew rate at unity gain		$\overline{}$			$\Delta V_I = 10 V$,	C _L = 100 pF,	See Figure 1	50*	70		V/μs

^{*} On products compliant to MIL-STD-883, Class B, this parameter is not production tested.

PARAMETER MEASUREMENT INFORMATION

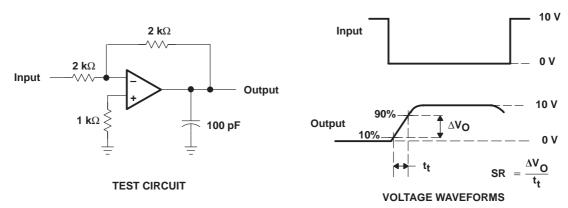


Figure 1. Slew Rate



[†] All characteristics are measured under open-loop conditions with common-mode input voltage unless otherwise specified.

 $[\]ddagger$ Full range for LM118 is -55° C to 125 $^{\circ}$ C, full range for LM218 is -25° C to 85 $^{\circ}$ C, and full range for LM318 is 0 $^{\circ}$ C to 70 $^{\circ}$ C.

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